

八十五學年度 電機/電子系(所) 丙 組碩士班研究生入學考試

科目 電子學 科號 3102 共 4 頁第 1 頁 *請在試卷【答案卷】內作答

1. Sketch Bode plots for the magnitude of the following transfer function:

$$T(s) = 10^4(1+s/10^5)(1+s/10^3)^{-1}(1+s/10^4)^{-1}$$

From your sketches determine approximate values for the magnitude at $\omega = 10^6$ rad/sec. (10%)

2. For the circuit in the following figure, let $R_B = 100\text{K}\Omega$, $R_C = 10\text{K}\Omega$, $V_{CC} = V_{EE} = 10\text{V}$, and let the BJT have $\beta = 100$ and $V_A = 100\text{V}$. Find the values of

- (a) V_B , (1%)
- (b) V_E , (1%)
- (c) I_C , (1%)
- (d) V_C , (1%)

V_A is the Early voltage

Also, find the values of the small-signal model parameters (at room temperature)

- (e) g_m , (2%)
- (f) r_e , (1%) r_e (emitter resistance $= \frac{V_T}{I_E}$)
- (g) r_π , (2%)
- (h) r_u , (1%) r_u (input resistance $= \frac{V_{CE}}{I_B}$)

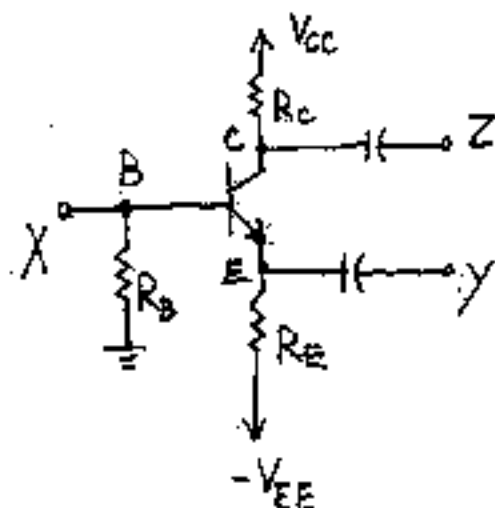
at the bias point.

When connected in the common emitter configuration with $R_S = R_L = 10\text{K}\Omega$, find the values of

- (i) R_i , (2.5%)
- (j) R_o , (2.5%)
- (k) A_v , (2.5%)
- (l) A_i , (2.5%)

R_S : source resistance

R_L : load resistance

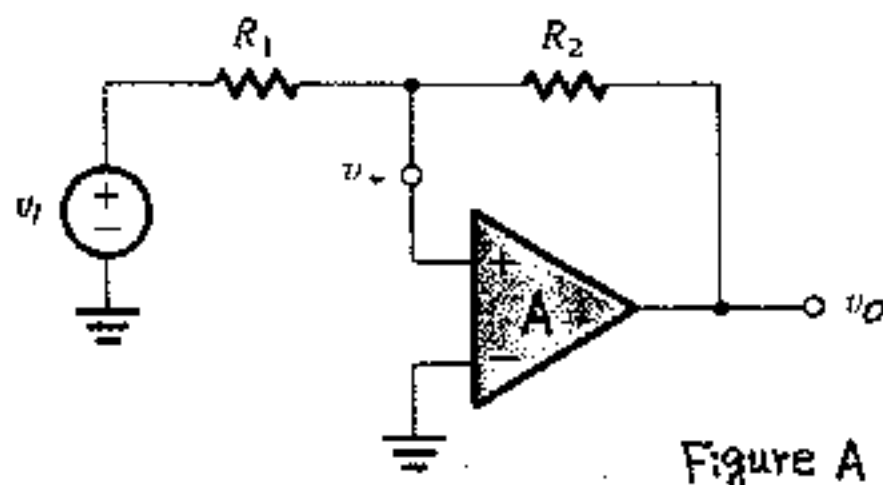


八十五學年度 電機、電子系(所) 丙 組碩士班研究生入學考試

科目 電子學 科號 3102 共 4 頁第 2 頁 *請在試卷【答案卷】內作答

3. A circuit as shown in figure A consists of an ideal operational amplifier A, two resistors R_1 and R_2 , and an input signal source v_1 . Assuming that the operational amplifier is powered by $\pm V_m$ and its output voltage limits are 1V short of the power rail voltages.

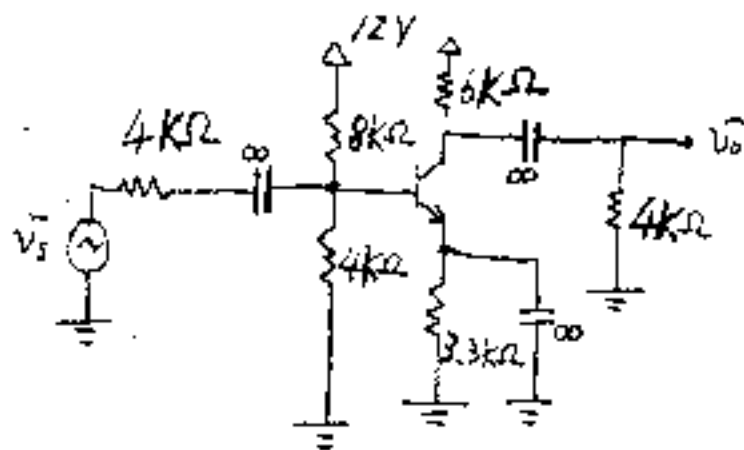
- Analyze the circuit behaviors, and plot the voltage transfer characteristics (v_o versus v_1), indicate all the voltages intersecting both v_o and v_1 axes in terms of V_m , R_1 , and R_2 . (8%)
- From the results obtained in part (a), can you identify and give the common well-known name of the circuit? (2%)
- In your analysis in part (a), can you use the virtual ground concept which is often employed in analyzing circuits that contain operational amplifiers? Your answer must give supporting reasoning. (4%)
- If the circuit is intended to be used as a waveform shaping circuit, that is to shape a sinusoidal wave of $v_1 = A_m \sin \omega t$ into a square wave at output v_o with an amplitude of B_m , what is the maximum of B_m ? And what is the design constraint on the relation among the parameters B_m , R_1 , R_2 , and A_m ? (6%)



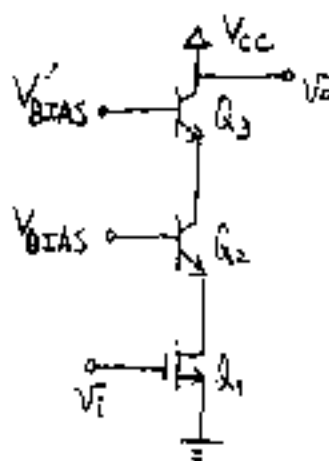
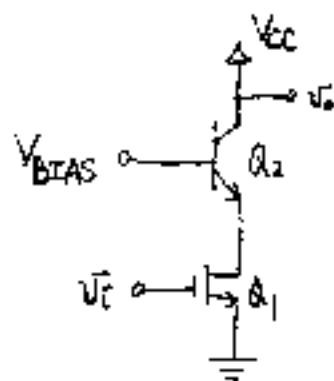
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科目 電子學 科號 3102 共 4 頁第 3 頁 *請在試卷【答案卷】內作答

4. Estimate the high-band corner frequency ω_H for the following circuit. Assume that $\beta = 100$ and $c_x = 10c_u = 1$ pF. (15%)



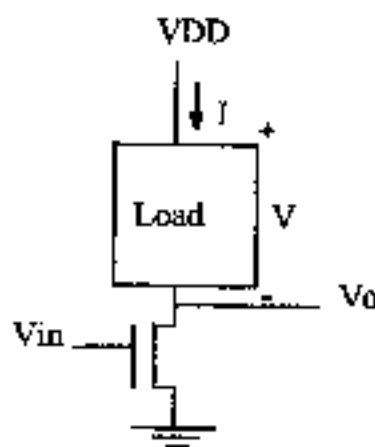
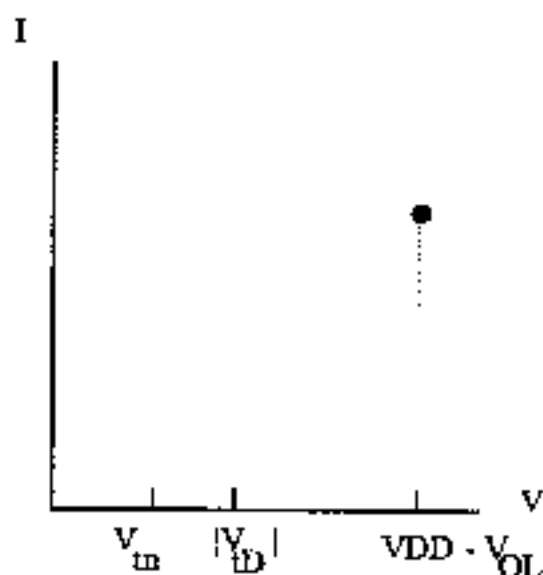
5. Explain why the output resistances of the following two cascode circuits are almost the same. (10%) How will you modify the circuits to obtain higher output resistances? (5%)



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科目 電子學 科號 3102 共 4 頁第 4 頁 *請在試卷【答案卷】內作答

6. (10%) (a) Draw the connections of the depletion-NMOS load (with threshold voltage V_{D0}), the enhancement-NMOS load (with threshold voltage V_{tn}), and the resistor load (with value R) inverters as shown below. (b) Draw the I-V curves of these three implementations. Assume that all three curves meet at a point with $V = V_{DD} - V_{OL}$.



7. (10%) Can you get an all pass filter from a (a) low-pass filter, (b) band-pass filter? Draw the circuit by using R , L , and C . (Hint: (a) first order and (b) second order)